

WAS7222Q

USB High speed (480Mbps), DPDT Analog Switch

Descriptions

The WAS7222Q is a high performance, double pole double throw (DPDT) CMOS analog switch that operates from a single +2.3V to +5.5V power supply.

The WAS7222Q is designed for switching of high-speed USB2.0 signals in handset and consumer applications, such as cell phones, digital cameras, and notebooks with hubs or controllers with limited USB I/Os.

The WAS7222Q has low bit-to-bit skew and high channel-to-channel noise isolation, and is compatible with various standards, such as high-speed USB 2.0 (480Mbps). Each switch is bi-directional and offers little attenuation of the high-speed signals at the outputs. Its bandwidth is quite marginal to pass high-speed USB 2.0 differential signals (480Mbps) with good signal integrity.

The WAS7222Q is featured with special circuitry on the D+/D-, which allows the device to withstand a VBUS short to D+ or D- when the USB devices are either powered off or on.

The SEL/OE pin has overvoltage protection that allows voltages above VCC, up to 7.0V to be present on the pin without damage or disruption of operation of the part, regardless of the operating voltage. The WAS7222Q is also featured with smart circuitry to minimize VCC leakage current even when SEL/OE control voltage is lower than VCC supply voltage. In other word, there is no need of additional device to shift SEL/OE level to be the same as that of VCC in real application.

The WAS7222Q is available in QFN1418-10L package. Standard products are Pb-Free and halogen-Free.

Applications

- Cell phones
- MID
- Router
- Other electronics equipments

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QFN1418-10L



Pin configuration (Top view)



Order information

Device	Package	Shipping
WAS7222Q-10/TR	QFN1418-10L	3000/Reel&Tape

Features

- Supply voltage : 2.3 ~ 5.5V
- -3dB Bandwidth : 550MHz @ C_L=5pF
- Off isolation : -36dB @ 250MHz
 - Crosstalk : -47dB @ 250MHz
- Low quiescent current : <1uA



Pin descriptions

Pin Number	Symbol	Descriptions	
1	D1+	Port A data 1 terminal, normally closed	
2	D2+	Port A data 2 terminal, normally open	
3	D+	Port A common data terminal, Connect to D1+ or D2+ according to SEL logic	
4	GND	Ground	
5	D-	Port B common data terminal, Connect to D1- or D2- according to SEL logic	
6	D2-	Port B data 2 terminal, normally open	
7	D1-	Port B data 1 terminal, normally closed	
8	ŌĒ	Enable control, Active low	
9	VCC	Power supply	
10	SEL	Switch select pin, digital logic low or high.	

Function descriptions

SEL	OE	Function
Х	Н	Bus switch disconnected
L	L	D+ connect to D1+ and D- connect to D1-
н	L	D+ connect to D2+ and D- connect to D2-

Logic symbol and typical applications



Logic Symbol

Typical Applications



Absolute maximum ratings

Parameter	Symbol	Value	Unit
Supply voltage range	VCC	-0.5 ~ 6.5	V
Data input/output voltage range	V _{DATA}	-0.5 ~ 6.5	V
Select input voltage range	V _{SEL}	-0.5 ~ 6.5	V
Continues output current	I _{OUT}	±50	mA
Junction temperature range	TJ	150	°C
Lead temperature range	TL	260	°C
Storage temperature range	T _{STG}	-65 ~ 150	°C
Thermal resistance	R _{θJA}	250	°C/W
ESD protection (HPM)	I/O to VCC, I/O to GND	±7000	V
ESD protection (HBM)	I/O to I/O	±5000	V

Recommend operating ratings

Parameter	Symbol	Value	Unit
Supply voltage range	VCC	2.3 ~ 5.5	V
Data input/output voltage range	V _{DATA}	0.0 ~ VCC	V
Select input voltage range	V _{SEL}	0.0 ~ VCC	V
Enable control input voltage range	V _{OE}	0.0 ~ VCC	V
Operating temperature range	T _A	-40 ~ 85	°C



Electronics Characteristics (Ta=25°C, VCC=4.5V, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Select and OF legic high level	V	VCC=3.0~4.5	1.7			V
Select and OE logic high level	V _{IH}	VCC=2.3~3.0	1.4			V
	N/	VCC=3.0~4.5			0.6	V
Select and OE logic low level	V _{IL}	VCC=2.3~3.0			0.4	V
		I _{ОUT} =0,				
Supply guidepoort ourront		V _{SEL} >1.5V or			1.0	uA
Supply quiescent current	I _{CC}	V _{SEL} <0.7V				
		Refer to figure1				
Select input leakage current	I _{SEL}	V _{SEL} =VCC			±1.0	uA
Off state switch leakage current	I _{OFF}	See figure 2			±1.0	uA
On state switch leakage current	I _{ON}	See figure 3			±1.0	uA
		VCC=3.0V,				Ω
On Registeres	Р	V _{DATA} =0~0.4V,		5.0	7.5	
On-Resistance	R _{ON}	I _{OUT} =8mA,		5.0	7.5	
		See figure 4				
		VCC=3.0V,			0.20	Ω
On-Resistance match		V _{DATA} =0~0.4V,		0.15		
	ΔR_{ON}	I _{OUT} =8mA,				
		See figure 4				
	R _{FLAT(ON)}	VCC=3.0V,			2.2	Ω
On-Resistance flatness		V _{DATA} =0~1.0V,		1.8		
On-Resistance namess		I _{OUT} =8mA,		1.0		
		See figure 4				
Propagation delay time	T _{PLH} / T _{PHL}	$C_L=10pF, R_L=50\Omega$		0.3	1.2	20
Fropagation delay time	PLH / PHL	See figure 5		0.5	1.2	ns
Select input to switch on time	T _{on}	$C_L=10pF, R_L=50\Omega$		75	120	ns
Select input to switch on time	I ON	See figure 6		15	120	115
Select input to switch off time	T _{OFF}	$C_L=10pF, R_L=50\Omega$		40	80	ns
Select input to switch on time	I OFF	See figure 6		40	00	115
Break-Before-Make time	T _{BBM}	Generated by design	0.5			ns
-3dB Bandwidth	BW	$R_L=50\Omega$, $C_L=5pF$		550		MHz
-Sub Danuwidin	DVV	$R_L=50\Omega$, $C_L=0pF$		800		
Off isolation	OIRR	R_L =50 Ω , F=250MHz		-36		dB
Crosstalk	Xtalk	$R_L=50\Omega$, F=250MHz		-47		dB
Charge injection	00	C _L =0.1nF, VCC=3.3V		5		nC
(Select input to common I/O)	Qg	$R_G=0\Omega$, $V_G=GND$		5		рС
Select pin input capacitance	C _{IN}	VCC=0V		5		pF
D1n, D2n, Dn Off capacitance		VCC=3.3V, <u>OE</u> =3.3V		5		pF
D1n, D2n, Dn On capacitance	C _{ON}	VCC=3.3V, OE=0V		6.5		pF



Typical Characteristics (Ta=25°C, VCC=4.5V, unless otherwise noted)







SEMI

Test Circuit



Conditions: V_{IN}=4.5V, VO=GND





Ron=V/IO







Conditions: V_{IN} =4.5V, V_O =Open

Figure 3: On state switch leakage current













Bandwidth (BW)



Off isolation (OIRR)



Crosstalk (Xtalk)



Package outline dimensions

QFN1418-10L





Cumhal	Dimension in Millimeters		
Symbol	Min.	Max.	
A	0.450	0.550	
A1	0.000	0.050	
A3	0.1	52 Ref.	
D	1.350	1.450	
E	1.750	1.850	
b	0.150	0.250	
е	0.400 Typ.		
L	0.350	0.450	
L1	0.450	0.550	